

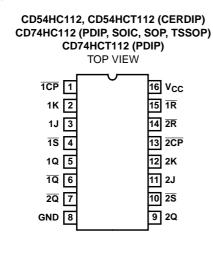
Data sheet acquired from Harris Semiconductor SCHS141H

March 1998 - Revised October 2003

Features

- Hysteresis on Clock Inputs for Improved Noise Immunity and Increased Input Rise and Fall Times
- Asynchronous Set and Reset
- Complementary Outputs
- Buffered Inputs
- Typical f_{MAX} = 60MHz at V_{CC} = 5V, C_L = 15pF, T_A = 25°C
- Fanout (Over Temperature Range)
 - Standard Outputs 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: $N_{IL} = 30\%$, $N_{IH} = 30\%$ of V_{CC} at $V_{CC} = 5V$
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, II \leq 1 μA at VOL, VOH

Pinout



CD54HC112, CD74HC112, CD54HCT112, CD74HCT112

Dual J-K Flip-Flop with Set and Reset Negative-Edge Trigger

Description

The 'HC112 and 'HCT112 utilize silicon-gate CMOS technology to achieve operating speeds equivalent to LSTTL parts. They exhibit the low power consumption of standard CMOS integrated circuits, together with the ability to drive 10 LSTTL loads.

These flip-flops have independent J, K, Set, Reset, and Clock inputs and Q and \overline{Q} outputs. They change state on the negative-going transition of the clock pulse. Set and Reset are accomplished asynchronously by low-level inputs.

The HCT logic family is functionally as well as pincompatible with the standard LS logic family.

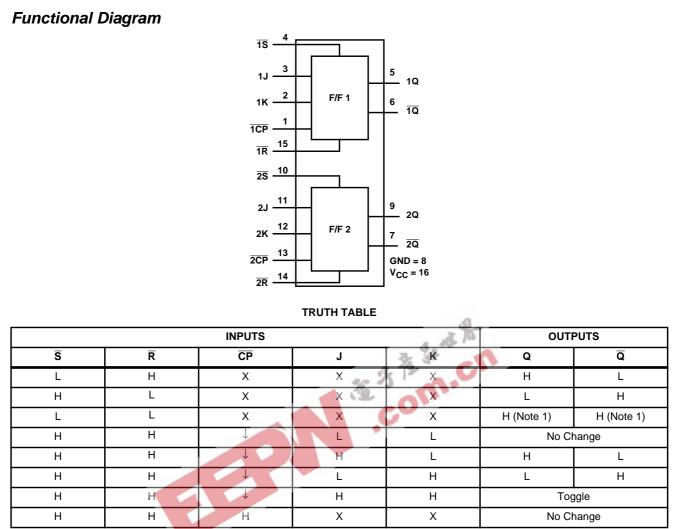
Ordering Information

PART NUMBER	TEMP. RANGE (^o C)	PACKAGE
CD54HC112F3A	-55 to 125	16 Ld CERDIP
CD54HCT112F3A	-55 to 125	16 Ld CERDIP
CD74HC112E	-55 to 125	16 Ld PDIP
CD74HC112MT	-55 to 125	16 Ld SOIC
CD74HC112M96	-55 to 125	16 Ld SOIC
CD74HC112NSR	-55 to 125	16 Ld SOP
CD74HC112PW	-55 to 125	16 Ld TSSOP
CD74HC112PWR	-55 to 125	16 Ld TSSOP
CD74HC112PWT	-55 to 125	16 Ld TSSOP
CD74HCT112E	-55 to 125	16 Ld PDIP

NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel. The suffix T denotes a small-quantity reel of 250.

CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

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H= High Level (Steady State)

L= Low Level (Steady State)

X= Don't Care

 \downarrow = High-to-Low Transition

NOTE:

1. Output states unpredictable if both \overline{S} and \overline{R} go High simultaneously after both being low at the same time.

Absolute Maximum Ratings

DC Supply Voltage, V _{CC}	:o 7V
For $V_{I} < -0.5V$ or $V_{I} > V_{CC} + 0.5V$	0mA
DC Drain Current, per Output, IO	
For -0.5V < V _O < V _{CC} + 0.5V±2	5mA
DC Output Diode Current, IOK	
For $V_0 < -0.5V$ or $V_0 > V_{CC} + 0.5V$	0mA
DC Output Source or Sink Current per Output Pin, IO	
For $V_0 > -0.5V$ or $V_0 < V_{CC} + 0.5V$	5mA
DC V _{CC} or Ground Current, I _{CC} ±5	0mA

Operating Conditions

Temperature Range, T _A 55 ^o C to 125 ^o C
Supply Voltage Range, V _{CC}
HC Types
HCT Types
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time, t _r , t _f
2V
4.5V 1.0ms (Max)
6V

Thermal Information

Package Thermal Impedance, θ_{JA} (see Note 2):

m.c

E (PDIP) Package
NS (SOP) Package64 ^o C/W
D (SOIC) Package73 ^o C/W
PW (TSSOP) Package 108°C/W
Maximum Junction Temperature (Hermetic Package or Die) . 175 ^o C
Maximum Junction Temperature (Plastic Package)
Maximum Storage Temperature Range
Maximum Lead Temperature (Soldering 10s)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

2. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

										_		
			ST)		25°C		-40 ⁰ C T	O 85 ⁰ C	-55 ⁰ C T	O 125 ⁰ C	
PARAMETER	SYMBOL	V ₁ (V)	I _O (mA)	V _{CC} (V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input VIH		-	2	1.5	-	-	1.5	-	1.5	-	V	
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input V _{IL} Voltage	VIL	-	-	2	-	-	0.5	-	0.5	-	0.5	V
			4.5	-	-	1.35	-	1.35	-	1.35	V	
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output V _{OH} Voltage CMOS Loads	V _{IH} or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V	
		VIL		4.5	4.4	-	-	4.4	-	4.4	-	V
				6	5.9	-	-	5.9	-	5.9	-	V
High Level Output			-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	V _{IH} or	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads		VIL		4.5	-	-	0.1	-	0.1	-	0.1	V
				6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output			-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	Ц	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μA

			ST ITIONS		25 ⁰ C			-40 [°] C TO 85 [°] C		25°C -40°C TO 85°		-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS				
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	4	-	40	-	80	μA				
HCT TYPES										•	-					
High Level Input Voltage	VIH	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V				
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V				
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V				
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V				
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	*	0.1	-	0.1	V				
Low Level Output Voltage TTL Loads			4	4.5	-	. *	0.26	C	0.33	-	0.4	V				
Input Leakage Current	lı I	V _{CC} and GND	-	5.5	- 23	C	±0.1	_	±1	-	±1	μA				
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5		-	4	-	40	-	80	μA				
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 3)	V _{CC} - 2.1		4.5 to 5.5	-	100	360	-	450	-	490	μΑ				

NOTE:

3. For dual-supply systems theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS
<u>1S, 2S</u>	0.5
1K, 2K	0.6
$\overline{1R}, \overline{2R}$	0.65
1J, 2J, 1CP, 2CP	1

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g., 360µA max at 25°C.

Prerequisite For Switching Specifications

MAX	UNITS
-	ns
-	ns
-	ns
•	

		TEST	v _{cc}		25 ⁰ C		-40 ⁰ C T	O 85 ⁰ C	-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Pulse Width \overline{R} , \overline{S}	t _W	-	2	80	-	-	100	-	120	-	ns
			4.5	16	-	-	20	-	24	-	ns
			6	14	-	-	17	-	20	-	ns
Setup Time J, K, to CP	t _{SU}	-	2	80	-	-	100	-	120	-	ns
			4.5	16	-	-	20	-	24	-	ns
			6	14	-	-	17	-	20	-	ns
Hold Time J, K, to \overline{CP}	t _H	-	2	0	-	-	0	-	0	-	ns
			4.5	0	-	-	0	-	0	-	ns
			6	0	-	-	0	-	0	-	ns
Removal Time \overline{R} to \overline{CP} , \overline{S} to \overline{CP}	t _{REM}	-	2	80	-	-	100	-	120	-	ns
			4.5	16	-	-	20	-	24	-	ns
			6	14	-	-	17	-	20	-	ns
CP Frequency	f _{MAX}	-	2	6	-		5	-	4	-	MHz
			4.5	30	- 35-		25	-	20	-	MHz
			6	35	人で		29	-	23	-	MHz
HCT TYPES				62							
Pulse Width CP	ts∪	-	4.5	16	C ^C		20	-	24	-	ns
Pulse Width \overline{R} , \overline{S}	t _W		4.5	18	-	-	23	-	27	-	ns
Setup Time J, K, to CP	tн	(🔶)`	4.5	16	-	-	20	-	24	-	ns
Hold Time J, K, to CP	tREM		4.5	3	-	-	3	-	3	-	ns
Removal Time \overline{R} to \overline{CP} , \overline{S} to \overline{CP}	t _W		4.5	20	-	-	25	-	30	-	ns
CP Frequency	f _{MAX}	-	4.5	30	-	-	25	-	20	-	MHz

Switching Specifications Input t_r, t_f = 6ns

		TEST V _{CC} 25°C -		-40 ⁰ C T	O 85 ⁰ C	-55 ⁰ C T					
PARAMETER	SYMBOL	CONDITIONS			ΤΥΡ	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES									-	_	
Propagation Delay,	t _{PLH} , t _{PHL}	$C_L = 50 pF$	2	-	-	175	-	220	-	265	ns
CP to Q, Q		C _L = 50pF	4.5	-	-	35	-	44	-	53	ns
		C _L = 15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	30	-	37	-	45	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	155	-	195	-	235	ns
\overline{S} to Q, \overline{Q}		C _L = 50pF	4.5	-	-	31	-	39	-	47	ns
		C _L = 15pF	5	-	13	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	26	-	33	-	40	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	180	-	225	-	270	ns
\overline{R} to Q, \overline{Q}		C _L = 50pF	4.5	-	-	36	-	45	-	54	ns
		C _L = 15pF	5	-	15	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	31	-	38	-	46	ns

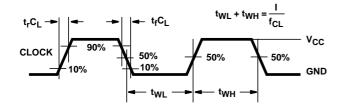
		TEST	vcc		25 ⁰ C		-40 ^о С Т	O 85 ⁰ C	-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
		C _L = 50pF	4.5	-	-	15	-	19	-	22	ns
		C _L = 50pF	6	-	-	13	-	16	-	19	ns
Input Capacitance	Cl	-	-	-	-	10	-	10	-	10	pF
CP Frequency	f _{MAX}	C _L = 15pF	5	-	60	-	-	-	-	-	MHz
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5	-	12	-	-	-	-	-	pF
HCT TYPES											
Propagation Delay,	^t PLH ^{, t} PHL	$C_L = 50 pF$	4.5	-	-	35	-	44	-	53	ns
\overline{CP} to Q, \overline{Q}		C _L = 15pF	5	-	14	-	-	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	32	-	40	-	48	ns
\overline{S} to Q, \overline{Q}		C _L = 15pF	5	-	13	-	-	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	37	S	46	-	56	ns
\overline{R} to Q, \overline{Q}		C _L = 15pF	5	-	14	1.1	I.P.	-	-	-	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	3	15		19	-	22	ns
Input Capacitance	Cl	-	-	20	2	10		10	-	10	pF
CP Frequency	f _{MAX}	CL = 15pF	5	C.	60		-	-	-	-	MHz
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}		5	-	20	-	-	-	-	-	pF

NOTES:

4. C_{PD} is used to determine the dynamic power consumption, per flip-flop.

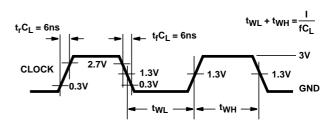
5. $P_D = C_{PD} V_{CC}^2 f_i + \Sigma C_L f_0$ where f_i = input frequency, f_0 = output frequency, C_L = output load capacitance, V_{CC} = supply voltage.

Test Circuits and Waveforms



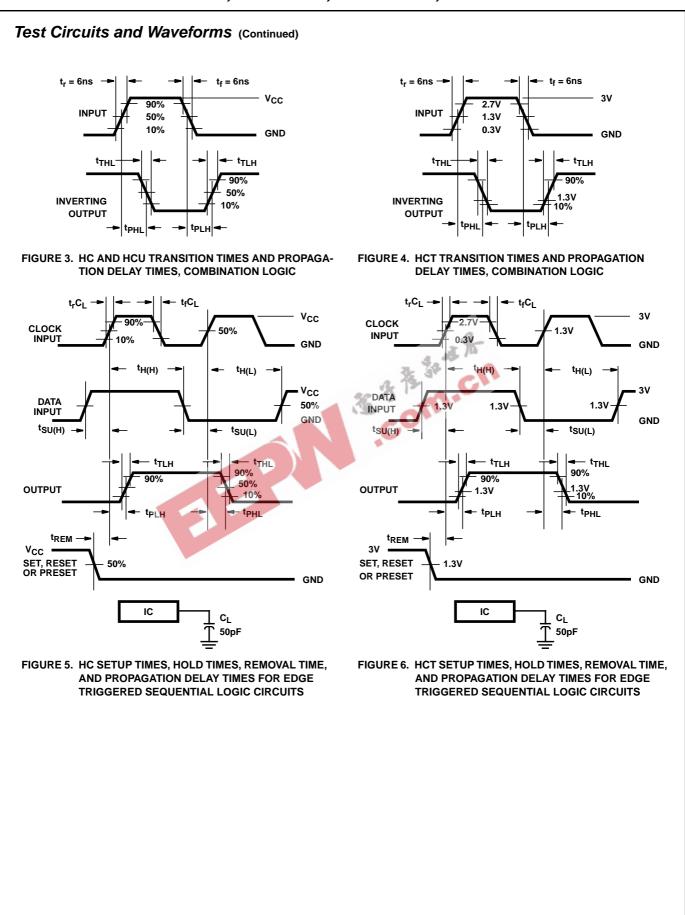
NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH



NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 2. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH





PACKAGE OPTION ADDENDUM

9-Oct-2007

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
5962-8970201EA	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HC112F3A	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HCT112F3A	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD74HC112E	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC112EE4	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC112M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112NSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112NSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112NSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112PW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112PWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112PWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112PWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112PWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112PWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112PWT	ACTIVE	TSSOP	PW	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112PWTE4	ACTIVE	TSSOP	PW	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC112PWTG4	ACTIVE	TSSOP	PW	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT112E	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT112EE4	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:





9-Oct-2007

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

3-5

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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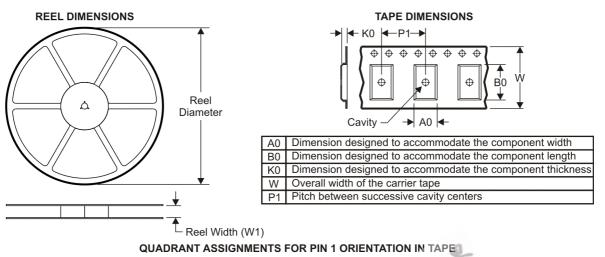
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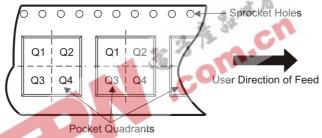


PACKAGE MATERIALS INFORMATION

19-Mar-2008

TAPE AND REEL INFORMATION



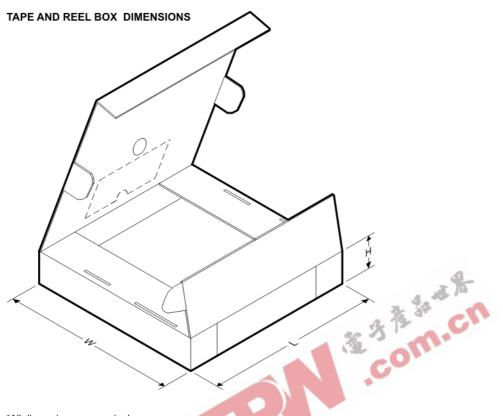


5	*All dimensions are nominal												
	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadra
	CD74HC112M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
	CD74HC112NSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
	CD74HC112PWR	TSSOP	PW	16	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1



PACKAGE MATERIALS INFORMATION

19-Mar-2008



*All dimensions are nominal

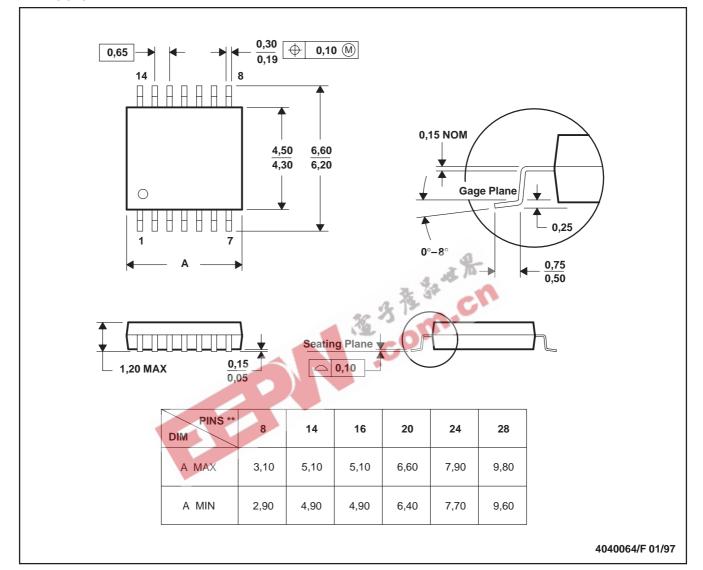
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC112M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HC112NSR	SO	NS	16	2000	346.0	346.0	33.0
CD74HC112PWR	TSSOP	PW	16	2000	346.0	346.0	29.0

MECHANICAL DATA

MTSS001C - JANUARY 1995 - REVISED FEBRUARY 1999

PLASTIC SMALL-OUTLINE PACKAGE

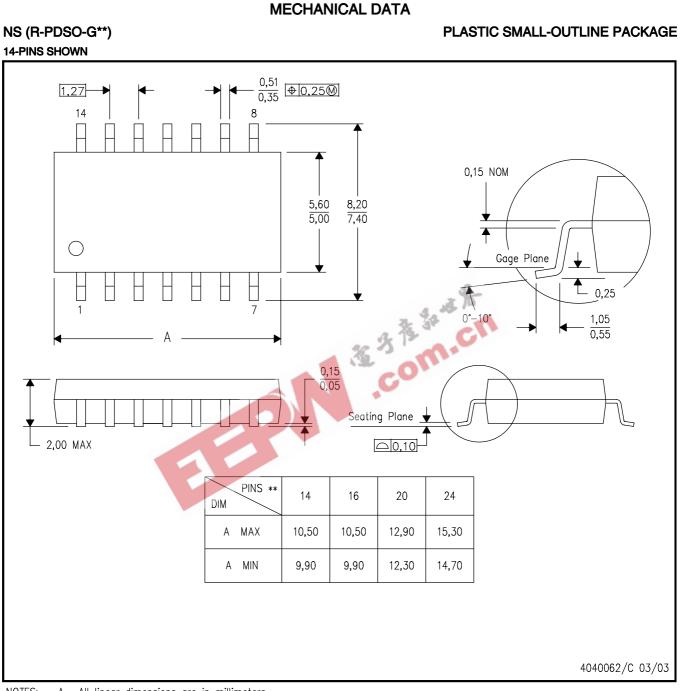




NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153





NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE

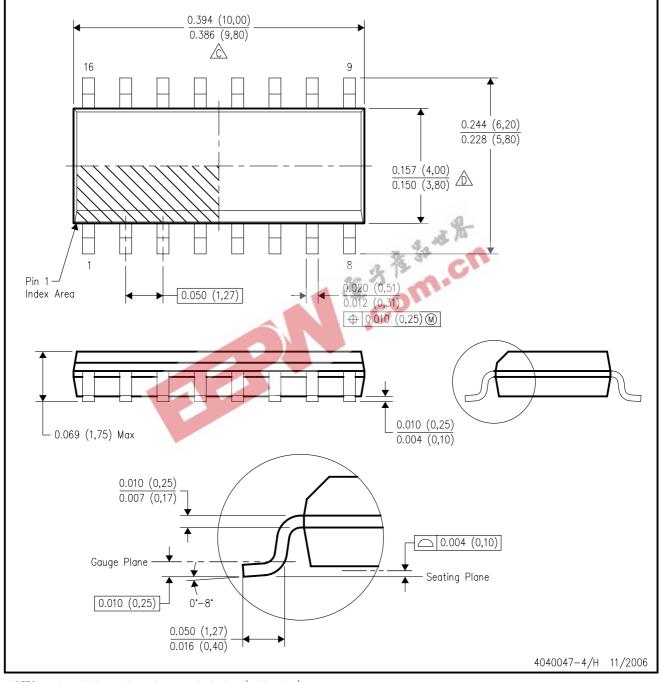
PINS ** 14 16 18 20 DIM 0.300 0.300 0.300 0.300 В А (7,62) (7,62) (7,62) (7,62) BSC BSC BSC BSC 8 14 0.785 1.060 .840 0.960 B MAX (19,94)(21, 34)(24, 38)(26, 92)B MIN С 0.300 0.300 0.310 0.300 C MAX (7, 62)(7,62) (7, 62)(7, 87)C MIN 7 0.245 0.245 0.220 0.245 0.065 (1,65) 0.045 (1,14) (6, 22)(6, 22)(5, 59)(6, 22)0.060 (1,52) - 0.005 (0,13) MIN Α -0.015 (0,38) 0.200 (5,08) MAX Seating Plane 0.130 (3,30) MIN 0.026 (0,66) 0.014 (0,36) 0°-15° 0.100 (2,54) 0.014 (0,36) 0.008 (0,20) 4040083/F 03/03

NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

D (R-PDSO-G16)

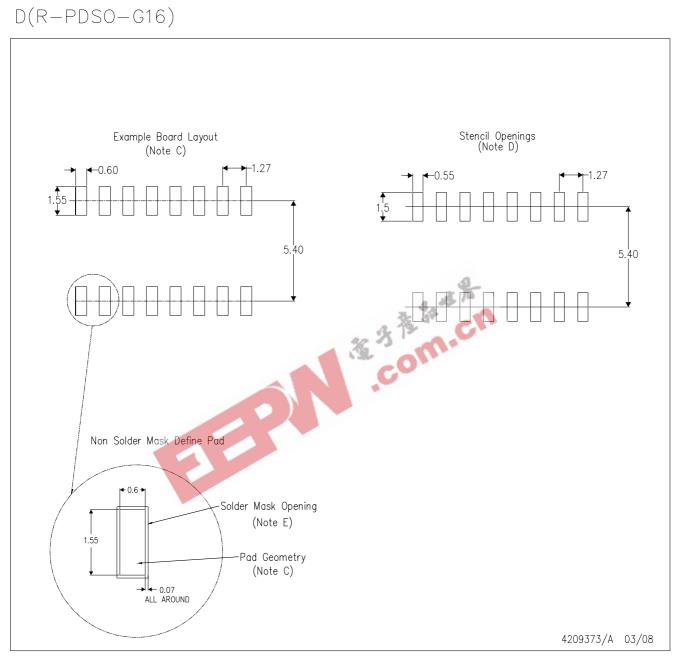
PLASTIC SMALL-OUTLINE PACKAGE



All linear dimensions are in inches (millimeters). NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- 🖄 Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side. E. Reference JEDEC MS-012 variation AC.





NOTES: A. All linear dimensions are in millimeters.

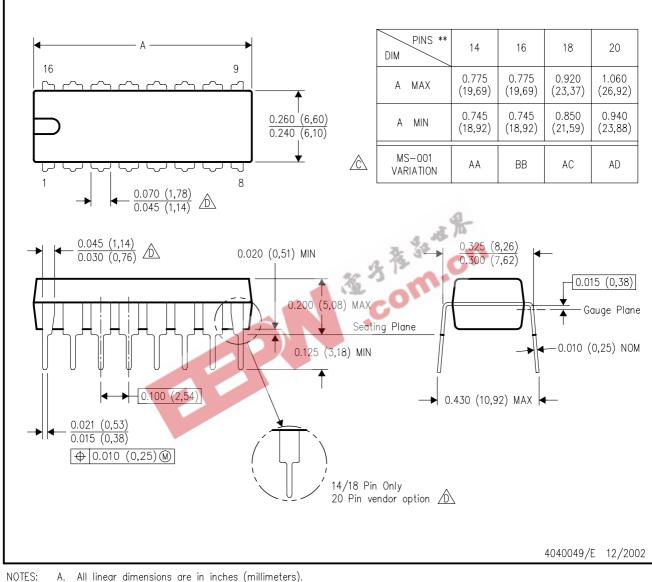
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.

- \triangle Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



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